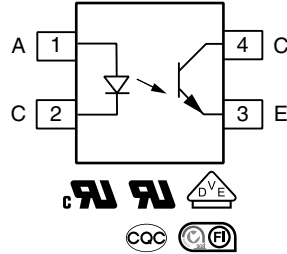


# Optocoupler, Phototransistor Output, Low Input Current, SSOP-4, Half Pitch, Mini-Flat Package



22628-1



## FEATURES

- High CTR with low input current
- Low profile package (half pitch)
- High collector emitter voltage,  $V_{CEO} = 80\text{ V}$
- Isolation test voltage =  $3750\text{ V}_{RMS}$
- Low coupling capacitance
- High common mode transient immunity
- Material categorization:  
For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



## DESCRIPTION

The VOS617A series has a GaAs infrared emitting diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a 4-pin 50 mil lead pitch mini-flat package.

It features a high current transfer ratio at low input current, low coupling capacitance, and high isolation voltage.

The coupling devices are designed for signal transmission between two electrically separated circuits.

## APPLICATIONS

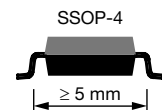
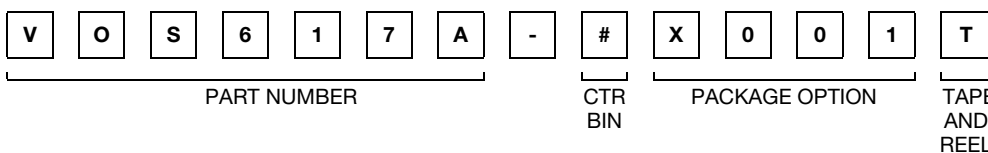
- Telecom
- Industrial controls
- Battery powered equipment
- Office machines
- Programmable controllers

## AGENCY APPROVALS

(All parts are certified under base model VOS617A)

- UL1577, file no. E52744
- cUL
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- FIMKO EN 60065, EN 60950-1
- CQC GB4943.1-2011 and GB8898-2011 (suitable for installation altitude below 2000 m)

## ORDERING INFORMATION



AGENCY CERTIFIED/ PACKAGE	CTR (%)						
	5 mA						
UL, cUL, FIMKO, CQC	50 to 600	63 to 125	100 to 200	160 to 320	80 to 160	130 to 260	200 to 400
SSOP-4, 50 mil pitch	VOS617AT	VOS617A-2T	VOS617A-3T	VOS617A-4T	VOS617A-7T	VOS617A-8T	VOS617A-9T
UL, CUL, FIMKO, CQC, VDE (option 1)	50 to 600	63 to 125	100 to 200	160 to 320	80 to 160	130 to 260	200 to 400
SSOP-4, 50 mil pitch	VOS617A- X001T	VOS617A- 2X001T	VOS617A- 3X001T	VOS617A- 4X001T	VOS617A- 7X001T	VOS617A- 8X001T	VOS617A- 9X001T

### Note

- Additional options may be possible, please contact sales office.

<b>ABSOLUTE MAXIMUM RATINGS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
<b>INPUT</b>				
Reverse voltage		$V_R$	6	V
Power dissipation		$P_{diss}$	70	mW
Forward current		$I_F$	50	mA
<b>OUTPUT</b>				
Collector emitter voltage		$V_{CEO}$	80	V
Emitter collector voltage		$V_{ECO}$	7	V
Collector current		$I_C$	50	mA
Power dissipation		$P_{diss}$	150	mW
<b>COUPLER</b>				
Isolation test voltage between emitter and detector	$t = 1\text{ min}$	$V_{ISO}$	3750	$V_{RMS}$
Total power dissipation		$P_{tot}$	170	mW
Storage temperature range		$T_{stg}$	- 55 to + 150	$^{\circ}\text{C}$
Ambient temperature range		$T_{amb}$	- 55 to + 110	$^{\circ}\text{C}$
Junction temperature		$T_j$	125	$^{\circ}\text{C}$
Soldering temperature <sup>(1)</sup>	$t = 10\text{ s}$	$T_{sld}$	260	$^{\circ}\text{C}$

**Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

<sup>(1)</sup> Refer to reflow profile for soldering conditions for surface mounted devices.



Fig. 1 - Power Dissipation vs. Ambient Temperature

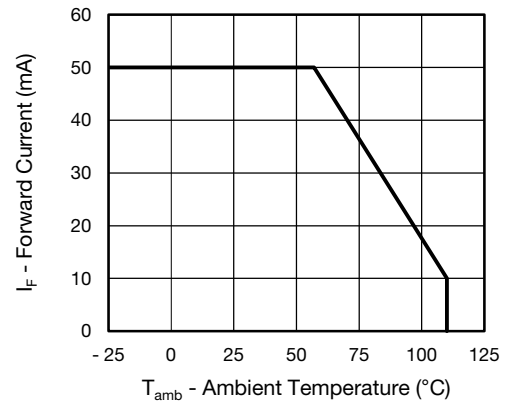


Fig. 2 - Forward Current vs. Ambient Temperature

**ELECTRICAL CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>INPUT</b>						
Forward voltage	$I_F = 50\text{ mA}$	$V_F$		1.18	1.5	V
Reverse current	$V_R = 6\text{ V}$	$I_R$		0.01	10	$\mu\text{A}$
Capacitance	$V_R = 0\text{ V}, f = 1\text{ MHz}$	$C_I$		7.3		pF
<b>OUTPUT</b>						
Collector emitter leakage current	$V_{CE} = 10\text{ V}$	$I_{CEO}$		0.3	100	nA
Collector emitter breakdown voltage	$I_C = 100\text{ }\mu\text{A}$	$BV_{CEO}$	80			V
Emitter collector breakdown voltage	$I_E = 10\text{ }\mu\text{A}$	$BV_{ECO}$	7			V
Collector emitter capacitance	$V_{CE} = 5\text{ V}, f = 1\text{ MHz}$	$C_{CE}$		5		pF
<b>COUPLER</b>						
Collector emitter saturation voltage	$I_F = 5\text{ mA}, I_C = 2.5\text{ mA}$	$V_{CEsat}$		0.25	0.4	V
Cut-off frequency	$I_F = 10\text{ mA}, V_{CC} = 5\text{ V}, R_L = 100\text{ }\Omega$	$f_{ctr}$		155		kHz

**Note**

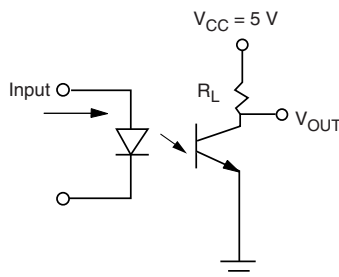
- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

**CURRENT TRANSFER RATIO** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
$I_C/I_F$	$I_F = 5\text{ mA}, V_{CE} = 5\text{ V}$	VOS617A	CTR	50		600	%
		VOS617A-2	CTR	63		125	%
		VOS617A-3	CTR	100		200	%
		VOS617A-4	CTR	160		320	%
		VOS617A-7	CTR	80		160	%
		VOS617A-8	CTR	130		260	%
		VOS617A-9	CTR	200		400	%

**SWITCHING CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>NON-SATURATED</b>						
Rise and fall time	$I_C = 2\text{ mA}, V_{CC} = 5\text{ V}, R_L = 100\text{ }\Omega$	$t_r$		3		$\mu\text{s}$
Fall time		$t_f$		3		$\mu\text{s}$
Turn-on time		$t_{on}$		6		$\mu\text{s}$
Turn-off time		$t_{off}$		4		$\mu\text{s}$
<b>SATURATED</b>						
Rise and fall time	$I_F = 1.6\text{ mA}, V_{CC} = 5\text{ V}, R_L = 1.9\text{ k}\Omega$	$t_r$		3		$\mu\text{s}$
Fall time		$t_f$		12		$\mu\text{s}$
Turn-on time		$t_{on}$		4		$\mu\text{s}$
Turn-off time		$t_{off}$		18		$\mu\text{s}$



isfh618a\_10

Fig. 3 - Test Circuit



isfh618a\_12

Fig. 4 - Test Circuit and Waveforms

SAFETY AND INSULATION RATINGS				
PARAMETER		SYMBOL	VALUE	UNIT
<b>MAXIMUM SAFETY RATINGS</b>				
Output safety power		$P_{SO}$	300	mW
Input safety current		$I_{si}$	200	mA
Safety temperature		$T_S$	150	°C
Comparative tracking index		CTI	175	
<b>INSULATION RATED PARAMETERS</b>				
Maximum withstanding isolation voltage		$V_{ISO}$	3750	$V_{RMS}$
Maximum transient isolation voltage		$V_{IOTM}$	6000	$V_{peak}$
Maximum repetitive peak isolation voltage		$V_{IORM}$	565	$V_{peak}$
Insulation resistance		$R_{IO}$	$10^{12}$	$\Omega$
$T_{amb} = 25\text{ °C}, V_{DC} = 500\text{ V}$				
Insulation resistance		$R_{IO}$	$10^{11}$	$\Omega$
$T_{amb} = 100\text{ °C}, V_{DC} = 500\text{ V}$				
Climatic classification (according to IEC 68 part 1)			55/110/21	
Environment (pollution degree in accordance to DIN VDE 0109)			2	
Creepage distance			$\geq 5$	mm
Clearance distance			$\geq 5$	mm
Insulation thickness			DTI	$\geq 0.4$ mm

**Note**

- As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

**TYPICAL CHARACTERISTICS** ( $T_{amb} = 25\text{ °C}$ , unless otherwise specified)


Fig. 5 - Forward Voltage vs. Forward Current

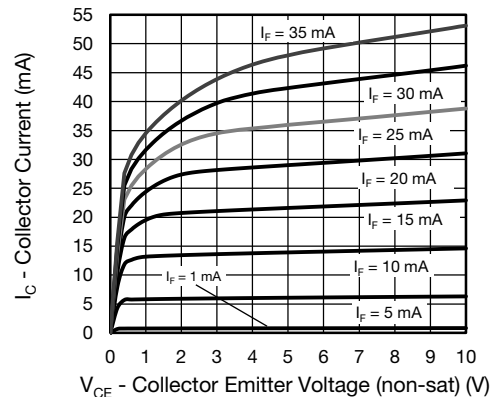


Fig. 6 - Collector Current vs. Collector Emitter Voltage



Fig. 7 - Leakage Current vs. Ambient Temperature

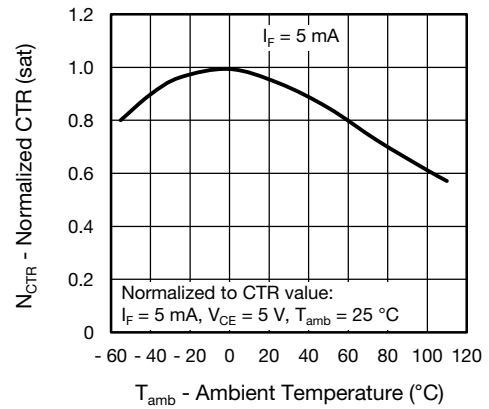


Fig. 10 - Normalized Current Transfer Ratio (saturated) vs. Ambient Temperature



Fig. 8 - Collector Current vs. Collector Emitter Voltage

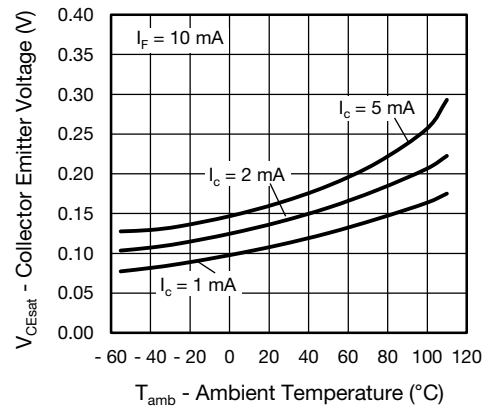


Fig. 11 - Collector Emitter Voltage vs. Ambient Temperature



Fig. 9 - Normalized Current Transfer Ratio (non-saturated) vs. Ambient Temperature

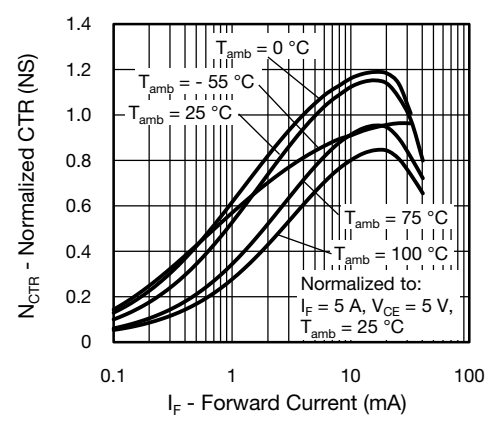


Fig. 12 - Normalized CTR (non-saturated) vs. Forward Current



Fig. 13 - Normalized CTR (saturated) vs. Forward Current



Fig. 15 -  $F_{CTR}$  vs. Collector Current



Fig. 14 -  $F_{CTR}$  vs. Phase Angle

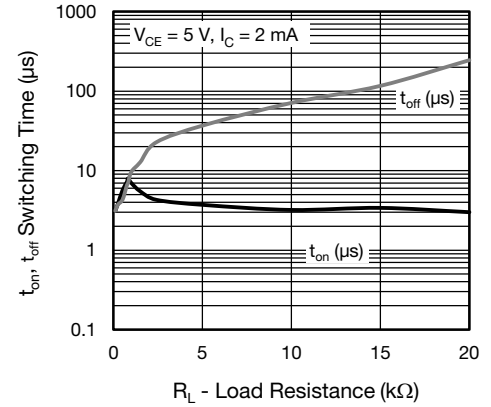
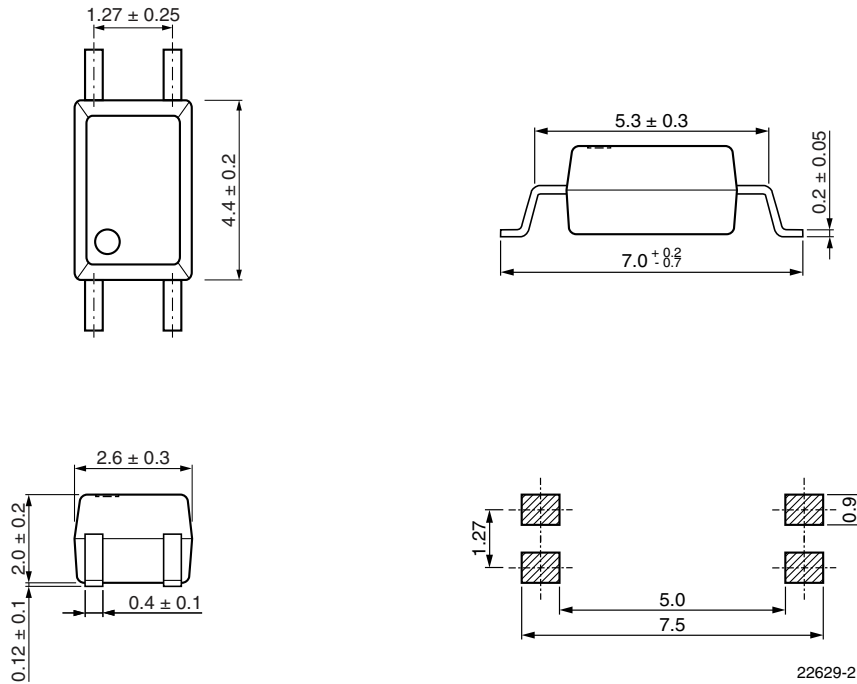
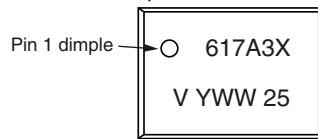


Fig. 16 - Switching Time vs. Load Resistance

**PACKAGE DIMENSIONS** in millimeters



**PACKAGE MARKING** (example of VOS617A-3X001T)



**Notes**

- VDE logo is not marked on option 1 parts, but indicated by “X”.
- Tape and reel suffix (T) is not part of the package marking.

**TAPE AND REEL DIMENSIONS** in millimeters

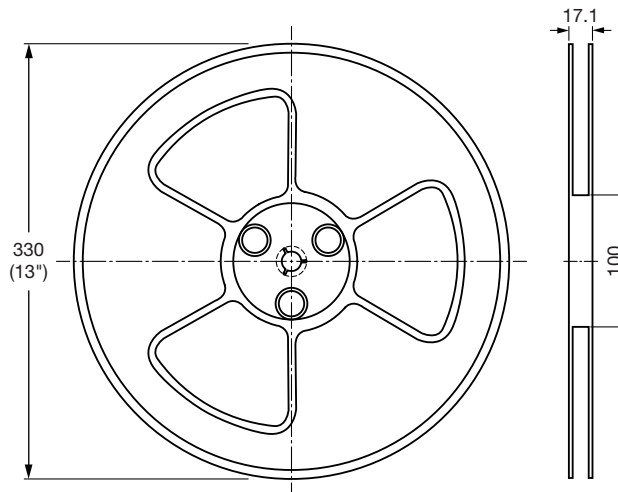


Fig. 17 - Reel Dimensions (3000 units per reel)

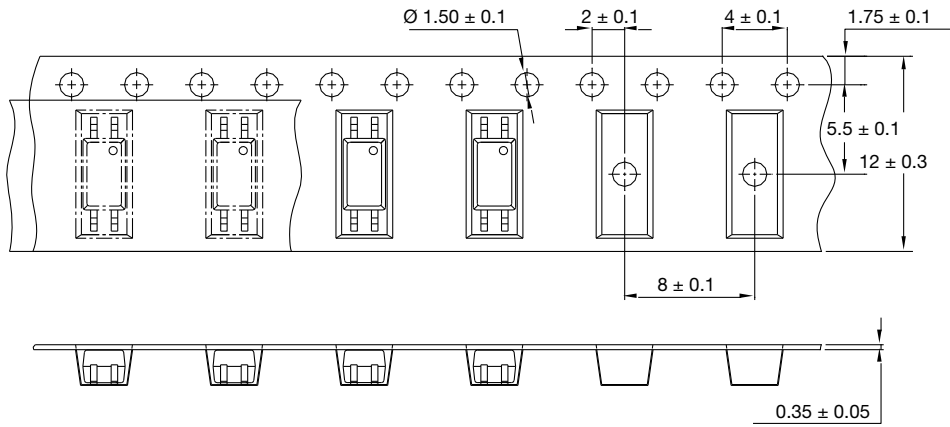


Fig. 18 - Tape Dimensions





## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

## Material Category Policy

**Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.**

**Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.**

**Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.**



## Стандарт Электрон Связь

Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию .

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России , а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научно-исследовательскими институтами России.

С нами вы становитесь еще успешнее!

### Наши контакты:

**Телефон:** +7 812 627 14 35

**Электронная почта:** [sales@st-electron.ru](mailto:sales@st-electron.ru)

**Адрес:** 198099, Санкт-Петербург,  
Промышленная ул, дом № 19, литера Н,  
помещение 100-Н Офис 331